

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of:

INVENTORS: Fletcher et al.

SERIAL NO.: To be assigned                   ART UNIT:

FILED: herewith                           EXAMINER:

TITLE: PIN Detector Apparatus and Method of Fabrication

ATTORNEY DOCKET NO.: 901.0120.U1(US)

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to Sections 609 and 707.05(b) of the MPEP and 37 CFR 1.97-1.99, copies are herewith submitted of documents which may be pertinent to the invention as claimed in the above-identified application. The attached form PTO-1449 lists these documents.

The citation of these documents should not be construed as a representation that a thorough search has been made, or that other, more pertinent material is not available.

Respectfully submitted,



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<b>INFORMATION DISCLOSURE CITATION FORM FOR PATENT APPLICATION (FORM PTO-1449) (Substitute)</b>		Docket No.: 901.0120.U1(US)	Serial No.: To be assigned		
		Applicant(s): Fletcher et al..			
		Filing Date: herewith	Group: N/A		
<b>U.S. PATENT DOCUMENTS</b>					
Examiner Initials	Document Number (Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name of Patentee or Applicant	Class	Sub-class
	US-4,782,028 US-5,137,837 US-5,807,771 US-6,072,224 US-6,617,646 B2 US- US- US- US- US- US- US- US- US- US- US-	11-01-1988 08-11-1992 09-15-1998 06-06-2000 09-09-2003	Farrier et al. Chang et al. Vu et al. Tyson et al. Parab	437 437 438 257 257	003 021 154 443 347
<b>FOREIGN PATENT DOCUMENTS</b>					
Examiner Initials	Document Number (Country Code-Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name Of Patentee of Applicant	Translation? Yes/No/n/a	
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<b>OTHER DOCUMENTS (Author (Capitalize), Title, Date, Pages, Etc., if known)</b>					
	F. FOULON, L. ROUSSEAU, L. BABADJIAN, S. SPIRKOVITCH, A. BRAMBILLA and P. BERGONZO, "A New Technique for the Fabrication of Thin Silicon Radiation Detectors", pgs. 218-220, IEEE Transactions on Nuclear Science, Vol. 46, No. 3, June 1999,				
Examiner's Signature:			Date Considered:		
Initial if reference was considered, whether or not citation is in conformance with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).					